BLF6G38-25; BLF6G38S-25

WiMAX power LDMOS transistor
Rev. 4 — 1 September 2015

AMMPLEON

Product data sheet

Product profile 1.

1.1 General description

25 W LDMOS power transistor for base station applications at frequencies from 3400 MHz to 3800 MHz.

Typical performance

Typical RF performance at $T_{case} = 25$ °C in a class-AB production test circuit.

Mode of operation	f	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR _{885k}	ACPR _{1980k}
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
1-carrier N-CDMA[1]	3400 to 3600	28	4.5	15	24	-45 <mark>[2]</mark>	-61 <mark>2</mark>

^[1] Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

1.2 Features and benefits

- Typical 1-carrier N-CDMA performance (single carrier IS-95 with pilot, paging, sync and 6 traffic channels [Walsh codes 8 - 13]. PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz) at a frequency of 3400 MHz, 3500 MHz and 3600 MHz, a supply voltage of 28 V and an I_{Dq} of 225 mA:
 - Average output power = 4.5 W
 - ◆ Power gain = 15 dB
 - ◆ Drain efficiency = 24 %
 - ◆ ACPR_{885k} = -45 dBc in 30 kHz bandwidth
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (3400 MHz to 3800 MHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multicarrier applications in the 3400 MHz to 3800 MHz frequency range

^[2] Measured within 30 kHz bandwidth.

2. Pinning information

Table 2. Pinning

	Filling		
Pin	Description	Simplified outline	Graphic symbol
BLF6G38	-25 (SOT608A)		
1	drain		
2	gate	71	1 ,
3	source		2
		2	3 sym112
DI 50000	2 (2		Sylli112
BLF6G38	S-25 (SOT608B)		
1	drain		
2	gate		1 <u> </u>
3	source	<u>[1]</u> 3	2
			3
			sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF6G38-25	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT608A
BLF6G38S-25	-	ceramic earless flanged package; 2 leads	SOT608B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	8.2	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Туре	Тур	Max	Unit
R _{th(j-case)}	thermal resistance from	T_{case} = 80 °C;	BLF6G38-25	1.8	_	K/W
	junction to case	$P_{L} = 25 \text{ W}$	BLF6G38S-25	1.8	-	K/W

BLF6G38-25_BLF6G38S-25#4

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.4 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 40 mA	1.4	2	2.4	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	1.5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	6	8.2	-	Α
I_{GSS}	gate leakage current	V_{GS} = +11 V; V_{DS} = 0 V	-	-	150	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 1.4 A	-	2.8	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.4 \text{ A}$	-	0.37	0.58	Ω
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V};$ f = 1 MHz	-	0.59	-	pF

7. Application information

Table 7. Application information

Mode of operation: 1-carrier N-CDMA; single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13); PAR = 9.7 dB at 0.01 % probability on the CCDF; channel bandwidth is 1.2288 MHz; f_1 = 3400 MHz; f_2 = 3500 MHz; f_3 = 3600 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 225 mA; T_{case} = 25 °C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 4.5 \text{ W}$	12.5	15	-	dB
RLin	input return loss	$P_{L(AV)} = 4.5 W$	-	-10	-	dB
η_{D}	drain efficiency	$P_{L(AV)} = 4.5 W$	22	24	-	%
ACPR _{885k}	adjacent channel power ratio (885 kHz)	$P_{L(AV)} = 4.5 \text{ W}$ [1]	-	-45	-40	dBc
ACPR _{1980k}	adjacent channel power ratio (1980 kHz)	$P_{L(AV)} = 4.5 \text{ W}$ [1]	-	-61	-56	dBc

^[1] Measured within 30 kHz bandwidth.

7.1 Ruggedness in class-AB operation

The BLF6G38-25 and BLF6G38S-25 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 225 \text{ mA}$; $P_L = P_{L(1dB)}$; f = 3600 MHz.

7.2 Ampleon WiMAX signal

7.2.1 WiMAX signal description

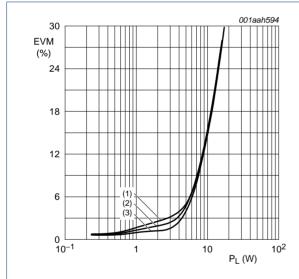
frame duration = 5 ms; bandwidth = 10 MHz; sequency = 1 frame; frequency band = WCS; sampling rate = 11.2 MHz; n = 8 / 7; G = T_g / T_b = 1 / 8; FFT = 1024; zone type = PUSC; δ = 97.7 %; number of symbols = 46; number of subchannels = 30; PAR = 9.5 dB.

Preamble: 1 symbol \times 30 subchannels; $P_L = P_{L(nom)} + 3.86 \text{ dB}$

Table 8. Frame structure

Frame o	ontent	s	Modulation technique	Data length
Zone 0	FCH	2 symbols × 4 subchannels	QPSK1/2	3
Zone 0	data	2 symbols × 26 subchannels	64QAM3/4	692
Zone 0	data	44 symbols × 30 subchannels	64QAM3/4	10000

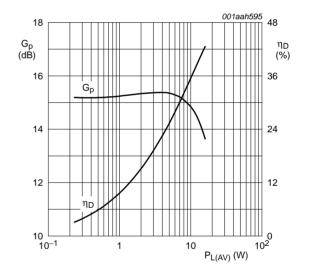
7.2.2 Graphs



 V_{DS} = 28 V; I_{Dq} = 225 mA; OFDMA signal; frame duration = 5 ms; bandwidth = 10 MHz; frequency band = WCS; n = 28 / 25; G = 1 / 8; FFT = 1024; zone type = PUSC; number of symbols = 46; number of subchannels = 30.

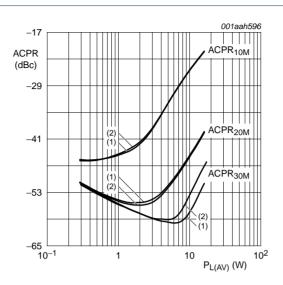
- (1) f = 3400 MHz
- (2) f = 3500 MHz
- (3) f = 3600 MHz

Fig 1. EVM as function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 225 mA; f = 3500 MHz; OFDMA signal; frame duration = 5 ms; bandwidth = 10 MHz; frequency band = WCS; n = 28 / 25; G = 1 / 8; FFT = 1024; zone type = PUSC; number of symbols = 46; number of subchannels = 30.

Fig 2. Power gain and drain efficiency as functions of average load power; typical values



 V_{DS} = 28 V; I_{Dq} = 225 mA; f = 3500 MHz; OFDMA signal; frame duration = 5 ms; bandwidth = 10 MHz; frequency band = WCS; n = 28 / 25; G = 1 / 8; FFT = 1024; zone type = PUSC; number of symbols = 46; number of subchannels = 30.

- (1) Low frequency component
- (2) High frequency component

Fig 3. Adjacent channel power ratio as function of average load power; typical values

7.3 Single carrier N-CDMA broadband performance at 9 W average

7.3.1 Graphs

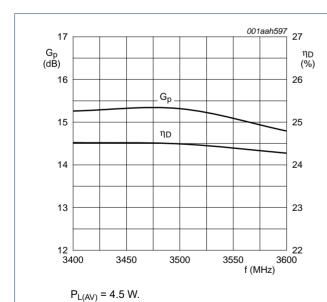
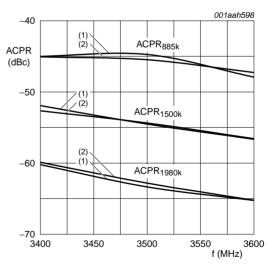


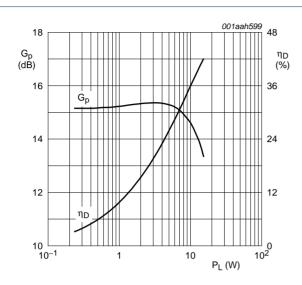
Fig 4. Power gain and drain efficiency as functions of frequency; typical values



 V_{DS} = 28 V; I_{Dq} = 350 mA; $P_{L(AV)}$ = 4.5 W; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; IBW = 30 kHz.

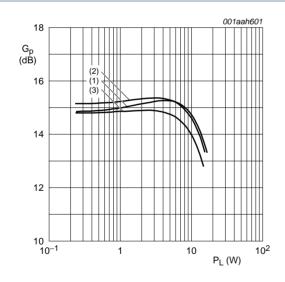
- (1) Low frequency component
- (2) High frequency component

Fig 5. Adjacent channel power ratio as function of frequency; typical values



 V_{DS} = 28 V; I_{Dq} = 225 mA; f = 3500 MHz; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; channel bandwidth = 1.23 MHz; IBW = 30 kHz.

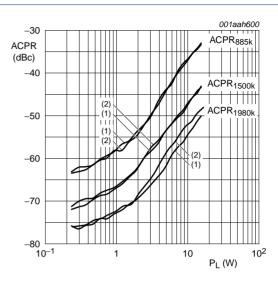
Fig 6. Power gain and drain efficiency as functions of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 225 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; channel bandwidth = 1.23 MHz; IBW = 30 kHz.

- (1) f = 3400 MHz
- (2) f = 3500 MHz
- (3) f = 3600 MHz

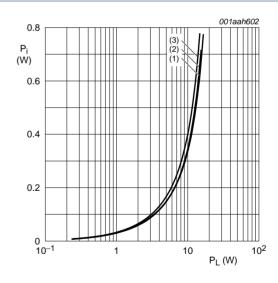
Fig 8. Power gain as function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 225 mA; f = 3500 MHz; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; channel bandwidth = 1.23 MHz; IBW = 30 kHz.

- (1) Low frequency component
- (2) High frequency component

Fig 7. Adjacent channel power ratio as function of average load power; typical values

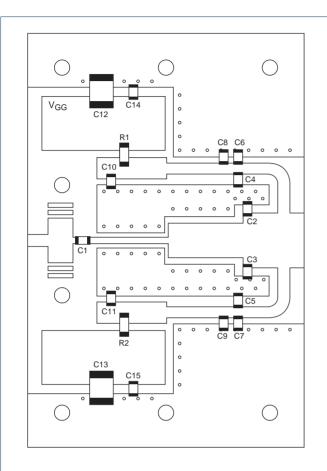


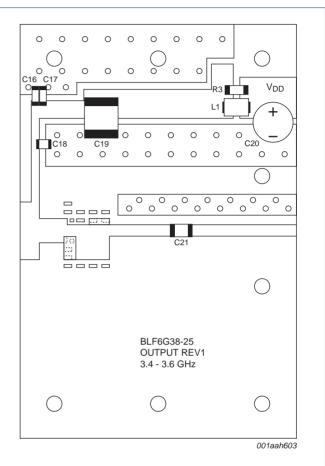
 V_{DS} = 28 V; I_{Dq} = 225 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; channel bandwidth = 1.23 MHz; IBW = 30 kHz.

- (1) f = 3400 MHz
- (2) f = 3500 MHz
- (3) f = 3600 MHz

Fig 9. Input power as function of load power; typical values

8. Test information





Striplines are on a double copper-clad Taconic RF35 Printed-Circuit Board (PCB) with ε_r = 3.5 and thickness = 0.76 mm. See Table 9 for list of components.

Fig 10. Component layout for 3400 MHz to 3600 MHz test circuit

Table 9. List of components (see Figure 10)

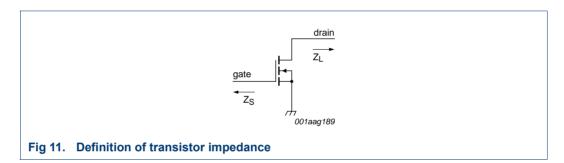
Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	22 pF	ATC 100A or equivalent
C2, C3	multilayer ceramic chip capacitor	3 pF	ATC 100A or equivalent
C4, C5, C6, C7, C8, C9, C18	multilayer ceramic chip capacitor	10 pF	ATC 100A or equivalent
C10, C11	multilayer ceramic chip capacitor	24 pF	ATC 100A or equivalent
C12, C13	multilayer ceramic chip capacitor	$4.7~\mu F;50~V$	TDK C4532X7R1H475M or equivalent
C14, C15	multilayer ceramic chip capacitor	1 nF	ATC 700A or equivalent
C16, C17	multilayer ceramic chip capacitor	100 nF	Vishay VJ1206Y104KXB or equivalent
C19	multilayer ceramic chip capacitor	10 μF ; 50 V	TDK C5750X7R1H106M or equivalent
C20	electrolytic capacitor	470 $\mu F;63~V$	
C21	multilayer ceramic chip capacitor	10 pF	ATC 100B or equivalent

Table 9. List of components (see Figure 10) ...continued

Component	Description	Value	Remarks
L1	ferrite SMD bead	-	Ferroxcube BDS3/3/4.6-4S2 or equivalent
R1, R2	SMD resistor	20 Ω	SMD 1206
R3	SMD resistor	9.1 Ω	SMD 1206

Table 10. Measured test circuit impedances

f	Z _S	Z _L
MHz	Ω	Ω
3400	14.65 + j29.87	13.46 + j3.58
3450	14.16 + j28.69	13.56 + j4.12
3500	14.56 + j30.52	13.76 + j4.74
3550	17.49 + j30.11	13.97 + j5.41
3600	15.50 + j29.36	14.16 + j5.95



9. Package outline

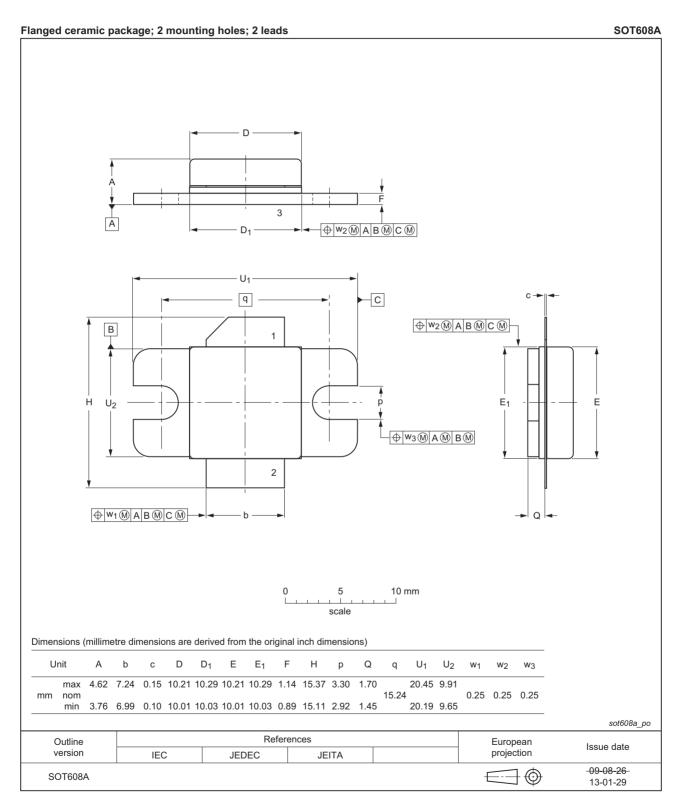


Fig 12. Package outline SOT608A

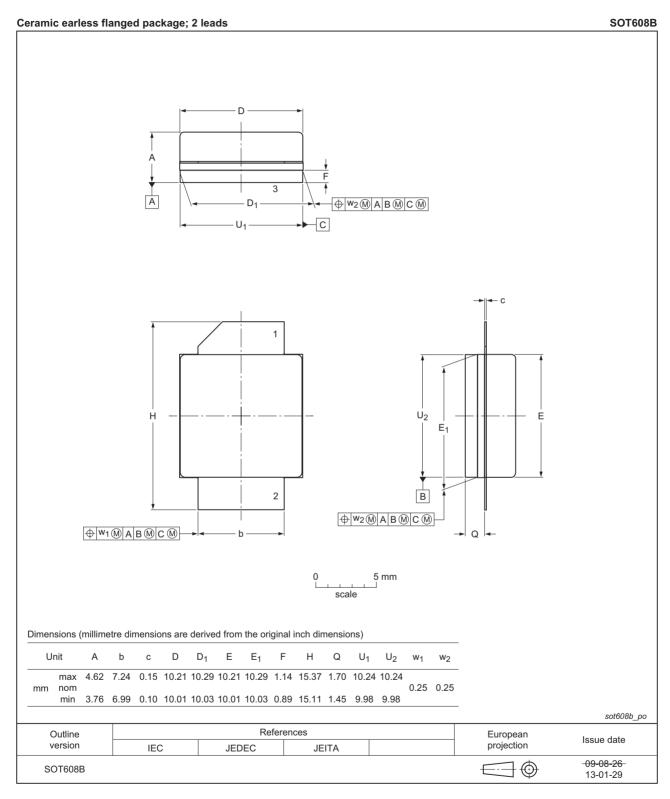


Fig 13. Package outline SOT608B

10. Abbreviations

Table 11. Abbreviations

and the theoretically		
Acronym	Description	
CCDF	Complementary Cumulative Distribution Function	
CW	Continuous Wave	
ESD	ElectroStatic Discharge	
EVM	Error Vector Magnitude	
FCH	Frame Control Header	
FFT	Fast Fourier Transform	
IBW	Instantaneous BandWidth	
IS-95	Interim Standard 95	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
N-CDMA	Narrowband Code Division Multiple Access	
OFDMA	Orthogonal Frequency Division Multiple Access	
PAR	Peak-to-Average power Ratio	
PUSC	Partial Usage of SubChannels	
RF	Radio Frequency	
QAM	Quadrature Amplitude Modulation	
QPSK	Quadrature Phase Shift Keying	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	
WCS	Wireless Communications Service	
WiMAX	Worldwide Interoperability for Microwave Access	
·		

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF6G38-25_BLF6G38S-25#4	20150901	Product data sheet	-	BLF6G38-25_BLF6G38S-25 v.3
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLF6G38-25_BLF6G38S-25 v.3	20130311	Product data sheet	-	BLF6G38-25_BLF6G38S-25_2
BLF6G38-25_BLF6G38S-25_2	20081223	Product data sheet	-	BLF6G38-25_BLF6G38S-25_1
BLF6G38-25_BLF6G38S-25_1	20080218	Preliminary data sheet	-	-

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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WiMAX power LDMOS transistor

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WiMAX power LDMOS transistor

14. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications
2	Pinning information 2
3	Ordering information
4	Limiting values 2
5	Thermal characteristics 2
6	Characteristics
7	Application information
7.1	Ruggedness in class-AB operation 3
7.2	Ampleon WiMAX signal 4
7.2.1	WiMAX signal description 4
7.2.2	Graphs 4
7.3	Single carrier N-CDMA broadband performance
	at 9 W average 5
7.3.1	Graphs
8	Test information 7
9	Package outline 9
10	Abbreviations11
11	Revision history
12	Legal information 12
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks13
13	Contact information
11	Contents 14

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